B.Tech. 5th Semester Electrical Engg.-I Examination December-2013

POWER ELECTRONICS

Paper-EE-317-F

Time allowed: 3 hours]

[Maximum marks:100

Note: Question No. 1 is compulsory from section A.

Attempt four questions from remaining four sections selecting one question from each section.

Section - A

- 1. (i) Draw and explain static V-I characteristic of a power diode.
 - (ii) Differentiate A.C. drives and D.C. drives.
 - (iii) Differentiate $\frac{dV}{dt}$ and $\frac{dI}{dt}$ protection of thyristors.
 - (iv) Explain SIT with their industrial application.
 - (v) Explain and draw characteristic of GTO 20

Section - B

- 2. (a) Explain role of power electronics in detail. 10
 - (b) Draw and explain ckt deagram, V-I characteristics and transfer characteristics of IGBT.

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- 3. For an SCR, gate cathode characteristic is given by $V_g = 1+10I_g$. Gate source voltage is a rectangular pulse of 15V with 20 μ sec duration. For an average gate power dissipation of 0.3 W and peak gate drive power of 5W, compute
 - (a) the resistance to be connected in series with the SCR gate.
 - (b) the triggering frequency.
 - (c) the duty cycle of the triggering pulse.

Section - C

- 4. Explain series and parallel operation of thyristors in detail.
- 5. Explain five thyristor Turn on methods in detail. 20

Section - D

- 6. (a) Explain three phase regulator.
 - (b) Design snubber circuits with explanation. 10
- 7. Explain voltage commutated chopper with current and voltage waveforms.

Section - E

8. (a) Explain three phase to single phase cycloconverters.

- (b) Derive o/p voltage equation for a cycloconverter.
- A single phase bridge inverter delivers power to a series connected RLC load with $R=2\Omega$ and $wL=10\Omega$. The periodic time T=0.1 msec. What value of C should the load have in order to obtain load commutation for the SCRs. The thyristor turn off time is 10 μ sec. Take circuit turn off time as 1.5tq. Assume that load current contains only fundamental component. 20